11.U1 4000 11:30 T36 4 CCC9U01

11-01-2005

1

CLAIMS

modifying electronic Method for а sample surface to analytical properties of comprising in situ deposition of neutral cesium (Cso), 5 under ultra-high vacuum, said neutral cesium being enabled in the form of a collimated adjustable stream, said Cso deposition being simultaneously accompanied by a primary bombardment of said surface, in the form of at least a beam comprising electrons and/or ions or neutral atoms or groups 10 of atoms, or by an X-ray irradiation, intended to induce a secondary emission or sputtering of particles for analysis, out of the surface, said sputtering comprising secondary electrons and/or Csxn1 and/or MCsxn4 positive clusters (x = 1, 2) and/or Mn- negative ions and/or Mn+ positive ions, M 15 being a constituent of the sample material made of an atom or a group of atoms | (n, m integers), the Cs° deposition being decoupled from the primary bombardment conditions, to provide a simultaneous optimization of deposited Cs0 concentration and analytical characteristics, such as the 20 depth resolution, characterized in that said optimized deposited Csº concentration is chosen only by adjusting the ratio ($\tau = v_{er}/v_p$) between the erosion rate (v_{er}) and the Cs⁰ deposition rate (v_D) , for a given sample and given primary bombardment conditions.

2. Method according to Claim 1, characterized, in that said optimized deposited Cs⁰ concentration is continuously adjustable according to the relation:

$$c_{cs} = \frac{1}{1 + (\tau - 1) \cdot \frac{\rho_M}{\rho_{cs}} + \frac{\tau}{Y}},$$

30 wherein ρ_M is the density of the sample constituent, ρ_{CS} the atomic density of the layer of Cs formed and Y the

11-01-2005 Control of the contro

2

sputtering yield characterizing the primary bombardment conditions for the sample considered.

- 3. Method according to Claim 1 2, characterized in that the stream of Cs0 is provided and 5 collimated in a column by means of :
 - a temperature adjustment of an evaporator comprising a metallic cesium reservoir, and/or
 - an aperture control of a motorized obturator located in the path of the cesium stream.
- 10 Method according to Claim З, characterized in that the reservoir temperature range is maintained between 70 and 90 °C, corresponding to a pressure range from 1.10-4 to 4.10-4 mbar and in that the stability of the deposition rate is about 2% over 15 minutes.
 - Method according to anyone of Claims 1 to 4, characterized in that it is coupled to static or dynamic Secondary Ion Mass Spectroscopy (SIMS), preferably operating in the MCs_x^+ mode (x = 1, 2).
- 20 б. Method according to Claim characterized in that the deposition rate of Cs0 continuously adjustable in the range from 0 to 10 A/s, corresponding about to 0 - 4 monolayers per second.
- 7. Method according to anyone of Claims 1 to 25 4, characterized in that it is coupled to electron spectroscopy.
- 8. Method according to Claim 7. characterized in that electron spectroscopy is selected from the group consisting of Auger Electron Spectroscopy 30 (AES), Electron Energy Loss Spectroscopy (EELS), X-Ray Photoemission Spectroscopy (XPS) and Photoemission Spectroscopy (UPS).

3

- Method according Claim 1, to characterized in that it further enables a stream of a chemical element other than Cs, evaporated under ultra-high vacuum, to create secondary emission for 5 purposes of $M_1M_2^{n+}$ clusters or M_2^{m-} ions or M_2^{m+} ions (n, m integers) or electrons, wherein M1 and M2 are respectively the atoms or groups of atoms constituted by the chemical element other than Cs and the atoms or groups of atoms from the sample.
- 10. Method according to Claim 1, characterized in that the sole adjustable deposition rate of Cs° or a chemical element other than Cs to an optimized value enables to optimize the intensity of secondary particles emitted by the sample.
- 15 11. Method according to Claim 1. characterized in that the useful yield, i.e. sensitivity of the secondary emission species, preferably M^{n-} , M^{m+} , and still more preferably Cs_x^{n+} and MCs_x^{n+} , approximately optimized solely by adjusting said ratio (τ) .
- 20 12. Method according to Claim 3, characterized in that the stream of Cs⁰ is automatically and continuously adapted via the obturator.
 - 13. Energy and/or mass analyzer instrument for carrying out the method according to anyone of the preceding Claims 1 to 12, comprising a neutral cesium (Cs°) deposition column, capable of delivering an adjustable and stable stream of pure neutral cesium, said neutral cesium simultaneously with being usable а primary bombardment or a primary irradiation column, and comprising an evaporation block (1) including a reservoir (5) filled equipped with temperature with pure metallic cesium, control means (6,7), prolongated by a tube (2,11) up to a gun end piece (13) located close to the sample and equipped

4

with beam collimation means (12), characterized in that said tube (2, 11) and gun end piece (13) equipped with beam collimation means (12) are further equipped with temperature control means (8,14,15) for preventing condensation and obturation risks.

14. Instrument according to Claim 13, characterized in that the evaporation block (1) is located in an external part which can be isolated from the main chamber (3) of the instrument by means of a gate valve (4) and capable of being separately pumped and vented.

15. Instrument according to Claim 13 or 14, characterized in that said beam collimation means comprise a motorized continuously adjustable obturator (12), preferably comprising a rotary disk using a slit of continuously variable width (16), said disk being driven by a stepper motor (17).

16. Instrument according to anyone of Claims
13 to 15, characterized in that, at the operation
temperature, the neutral cesium (Cs°) is in liquid state
20 and the evaporation block (1) lies with an inclination
angle such as said liquid remains in the bottom of the
reservoir (5) under gravity effect.

17. Instrument according to anyone of Claims 13 to 15, preferably a static or dynamic secondary ion mass spectrometry (SIMS) instrument, comprising a primary bombardment column and a secondary column equipped with secondary ion extraction means, a mass spectrometer, preferably of the type TOF (Time-Of-Flight), quadrupolar or with magnetic sector and ion detection means.

30